

**UTC** UNISONIC TECHNOLOGIES CO., LTD

# **BTA41**

Preliminary

# **40A STANDARD TRIAC**

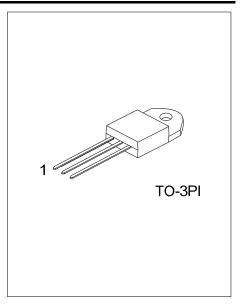
### DESCRIPTION

The UTC BTA41 is a 41A triacs which can be operated in 4 quadrants, it uses UTC's advanced technology to provide customers with high commutation performances, etc.

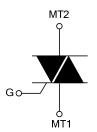
The UTC BTA41 is suitable for AC switching application and phase control application such as fan speed and temperature modulation control, lighting control and static switching relay, either in through-hole or surface-mount packages.

### **FEATURES**

- \* Low thermal resistance with clip bonding
- \* High current capability
- \* High commutation capability



### **SYMBOL**



# **ORDERING INFORMATION**

Ordering Number		Daakaga	Pin Assignment			Deeking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BTA41L-x-xx-T3I-T BTA41G-x-xx-T3I-T		TO-3PI	MT1	MT2	G	Tube	
Noto: Din Assignment: MT1: MT1 MT2: MT2 C: Coto							

Note: Pin Assignment: MT1: MT1 MT2: MT2 G: Gate

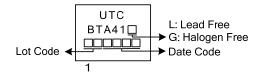
(2)Package Type (2) (3)Sensitivity and type (4) (4)Voltage (4)	<ol> <li>(1) T: Tube</li> <li>(2) T3I: TO-3PI</li> <li>(3) refer to SENSITIVITY AND TYPE</li> <li>(4) 6: 600V, 8: 800V</li> <li>(5) G: Halogen Free and Lead Free, L: Lead Free</li> </ol>
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#### SENSITIVITY AND TYPE

	VOL	TAGE		ТУРГ
PART NUMBER	600V	800V	SENSITIVITY	TYPE
В	Ô	$\odot$	50mA	STANDARD
○ <b>A</b> "L L L				

(i): Available

# MARKING





# ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
n-State RMS Current (Full Sine Wave) Tc=95°C		I <sub>T(RMS)</sub>	40	А
Non Repetitive Surge Peak On-State	On-State F=50Hz, t=20ms		400	А
Current (Full Cycle, Tյ initial=25°C)	F=60Hz, t=16.7ms	Ітѕм	420	А
I <sup>2</sup> t Value for Fusing	t <sub>p</sub> =10ms	l <sup>2</sup> t	1000	A <sup>2</sup> s
Critical Rate of Rise of On-State Current: I <sub>G</sub> =2xI <sub>GT</sub> , t <sub>r</sub> ≤100ns	F=120Hz, TJ=125°C	dl/dt	50	A/µs
Non Repetitive Surge Peak Off-State Voltage	t <sub>p</sub> =10ms, Tյ=25°C	V <sub>DSM</sub> /V <sub>RSM</sub>	V <sub>DSM</sub> / V <sub>RSM</sub> +100	V
Peak Gate Current	t <sub>p</sub> =20µs, Tյ=125°C	lgм	8	А
Average Gate Power Dissipation	TJ=125°C	P <sub>G(AV)</sub>	1	W
Storage Junction Temperature		Tstg	-40 ~ +150	°C
Operating Junction Temperature		TJ	-40 ~ +125	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## DEVICE SUMMARY

PARAMETER	SYMBOL	RATINGS	UNIT
On-State RMS Current	I <sub>T(RMS)</sub>	40	А
Repetitive Peak Off-State Voltage	VDRM/VRRM	600	V
Triggering Gate Current	I <sub>GT</sub>	50	mA

# THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ <sub>JA</sub>	50	°C/W
Junction to Case (AC)	θις	0.6	°C/W

## ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Cata Triagor Current (Note 1)	Igt		-  -			50	mA
Gate Trigger Current (Note 1)	IGI	V <sub>D</sub> =12V, R <sub>L</sub> =33Ω	IV			100	mA
Gate Trigger Voltage	Vgt		ALL			1.3	V
Gate Non-Trigger Voltage	$V_{\text{GD}}$	V <sub>D</sub> =V <sub>DRM</sub> , R <sub>L</sub> =3.3kΩ, T <sub>J</sub> =125°C	ALL	0.2			V
Holding Current (Note 2)	Ін	I⊤=500mA				80	mA
			I-111-1V			70	mA
Latching Current	١L	Ig=1.2IgT	II			160	mA
Critical Rate of Rise of Off-State	dV/dt	V <sub>D</sub> =67%V <sub>DRM</sub> , Gate Open,	L-125°C	500			V/µs
Voltage (Note 2)	uv/ut	VD-07 % VDRM, Gate Open,	IJ-125 C	300			v/µs
Critical Rate of Rise of Off-State	(d)//dt)c	$(dl/dt)_{c}=20.0/mc$ T = 125°C		10			V/ue
Voltage at Commutation (Note 2)	(dV/dt)c	(dl/dt)c=20A/ms, TJ=125°C		10			V/µs

# STATIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Peak On-State Voltage (Note 1)	VT	I <sub>ТM</sub> =60A, t <sub>P</sub> =380µs, TJ=25°С			1.55	V
Threshold Voltage (Note 2)	V <sub>TO</sub>	TJ=125°C			0.85	V
Dynamic Resistance (Note 2)	RD	TJ=125°C			10	mΩ
Deve attitude Develop Off Otata Ourseast	Idrm	V <sub>DRM</sub> =V <sub>RRM</sub> , T <sub>J</sub> =25°C			5	μA
Repetitive Peak Off-State Current	I <sub>RRM</sub>	V <sub>DRM</sub> =V <sub>RRM</sub> , T <sub>J</sub> =125°C			5	mA

Notes: 1. Minimum  $I_{\text{GT}}$  is guaranted at 5% of  $I_{\text{GT}}$  max.

2. For both polarities of MT2 referenced to MT1.



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